

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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DSA30C45PB

preliminary

 $V_{RRM} = 45V$

 $I_{FAV} = 2x \quad 15A$

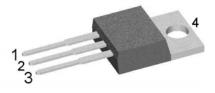
 $V_F = 0.63V$

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

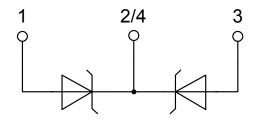
Schottky Diode Gen²

Part number

DSA30C45PB



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0





preliminary

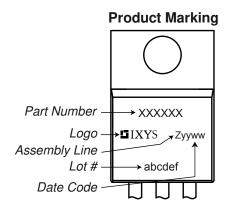
Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ing voltage	$T_{VJ} = 25^{\circ}C$			45	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			45	V
I _R	reverse current, drain current	V _R = 45 V	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 45 V$	$T_{VJ} = 125^{\circ}C$			2.5	mΑ
V _F	forward voltage drop	I _F = 15 A	$T_{VJ} = 25^{\circ}C$			0.75	V
		$I_F = 30 \text{ A}$				0.91	V
		I _F = 15 A	T _{VJ} = 125°C			0.63	V
		$I_F = 30 \text{ A}$				0.79	V
I _{FAV}	average forward current	T _c = 155°C	T _{vJ} = 175°C			15	Α
		rectangular d = 0.5					i I I I
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.42	V
r _F	slope resistance \(\) for power lo	oss calculation only				9.9	mΩ
R _{thJC}	thermal resistance junction to case	е				1.75	K/W
R _{thCH}	thermal resistance case to heatsing	nk			0.50		K/W
P _{tot}	total power dissipation		$T_C = 25^{\circ}C$			85	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			340	Α
C¹	junction capacitance	$V_R = 5 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		497		pF



DSA30C45PB

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Package TO-220				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I _{RMS}	RMS current	per terminal 1)			35	Α	
T _{VJ}	virtual junction temperature		-55		175	°C	
T _{op}	operation temperature		-55		150	°C	
T _{stg}	storage temperature		-55		150	°C	
Weight				2		g	
M _D	mounting torque		0.4		0.6	Nm	
F _c	mounting force with clip		20		60	N	



Part number

D = Diode

S = Schottky Diode

A = low VF

30 = Current Rating [A] C = Common Cathode

45 = Reverse Voltage [V] PB = TO-220AB (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA30C45PB	DSA30C45PB	Tube	50	503934

Similar Part	Package	Voltage class	
DSA30C45PC	TO-263AB (D2Pak) (2)	45	
DSA30C45HB	TO-247AD (3)	45	

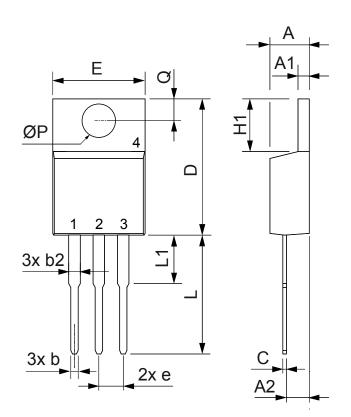
Equiva	alent Circuits for	Simulation	* on die level	T _{VJ} = 175 °C
$I \rightarrow V_0$	R_0	Schottky		
V _{0 max}	threshold voltage	0.42		V
R _{0 max}	slope resistance *	6.7		$m\Omega$



LIXYS

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Outlines TO-220



Dim.	Millimeter		Inches		
	Min.	Max.	Min.	Max.	
Α	4.32	4.82	0.170	0.190	
A1	1.14	1.39	0.045	0.055	
A2	2.29	2.79	0.090	0.110	
b	0.64	1.01	0.025	0.040	
b2	1.15	1.65	0.045	0.065	
С	0.35	0.56	0.014	0.022	
D	14.73	16.00	0.580	0.630	
Е	9.91	10.66	0.390	0.420	
е	2.54	BSC	0.100	BSC	
H1	5.85	6.85	0.230	0.270	
L	12.70	13.97	0.500	0.550	
L1	2.79	5.84	0.110	0.230	
ØP	3.54	4.08	0.139	0.161	
Q	2.54	3.18	0.100	0.125	

